NTJD1155L

Power MOSFET

8 V, ±1.3 A, High Side Load Switch with Level-Shift, P-Channel SC-88

The NTJD1155L integrates a P and N–Channel MOSFET in a single package. This device is particularly suited for portable electronic equipment where low control signals, low battery voltages and high load currents are needed. The P–Channel device is specifically designed as a load switch using ON Semiconductor state–of–the–art trench technology. The N–Channel, with an external resistor (R1), functions as a level–shift to drive the P–Channel. The N–Channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The NTJD1155L operates on supply lines from 1.8 to 8.0 V and can drive loads up to 1.3 A with 8.0 V applied to both $V_{\rm IN}$ and $V_{\rm ON/OFF}$.

Features

- Extremely Low R_{DS(on)} P-Channel Load Switch MOSFET
- Level Shift MOSFET is ESD Protected
- Low Profile, Small Footprint Package
- V_{IN} Range 1.8 to 8.0 V
- ON/OFF Range 1.5 to 8.0 V
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating			Symbol	Value	Unit	
Input Voltage (V _{DSS} , P-Ch)			V_{IN}	8.0	V	
ON/OFF Voltage (V _{GS} , N-	·Ch)		V _{ON/OFF}	8.0	V	
Continuous Load Current	Steady	T _A = 25°C	ΙL	±1.3	Α	
(Note 1)	State	T _A = 85°C		±0.9		
Power Dissipation	Steady	T _A = 25°C	P_{D}	0.40	W	
(Note 1)	State	T _A = 85°C		0.20		
Pulsed Load Current	t _p = 10 μs		I_{LM}	±3.9	Α	
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to 150	°C	
Source Current (Body Diode)			Is	-0.4	Α	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			T _L	260	°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	320	°C/W
Junction-to-Foot - Steady State (Note 1)	$R_{\theta JF}$	220	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Surface-mounted on FR4 board using 1 inch sq pad size (Cu area = 1.127 in sq [1 oz] including traces).

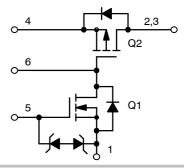


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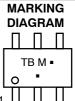
V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
	130 mΩ @ –4.5 V	
8.0 V	170 mΩ @ –2.5 V	±1.3 A
	260 mΩ @ -1.8 V	

SIMPLIFIED SCHEMATIC





SC-88 (SOT-363) CASE 419B STYLE 30

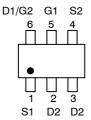


TB = Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT



ORDERING INFORMATION

Device	Package	Shipping [†]
NTJD1155LT1G	SC-88 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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NTJD1155L

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS					•		
Q2 Drain-to-Source Breakdown Voltage	V _{IN}	$V_{GS2} = 0 \text{ V}, I_{D2}$	= 250 μΑ	-8.0			V
Forward Leakage Current	I _{FL}	V _{GS1} = 0 V,	T _J = 25°C			1.0	μΑ
		$V_{DS2} = -8.0 \text{ V}$	T _J = 125°C			10	
Q1 Gate-to-Source Leakage Current	I _{GSS}	V _{DS1} = 0 V, V _{GS}	₁ = ±8.0 V			±100	nA
Q1 Diode Forward On-Voltage	V _{SD}	$I_S = -0.4 \text{ A}, V_G$	_{S1} = 0 V		-0.8	-1.1	V
ON CHARACTERISTICS							
ON/OFF Voltage	V _{ON/OFF}			1.5		8.0	V
Q1 Gate Threshold Voltage	V _{GS1(th)}	$V_{GS1} = V_{DS1}, I_D = 250 \mu A$		0.4		1.0	V
Input Voltage	V _{IN}	$V_{GS1} = V_{DS1}, I_D = 250 \mu A$		1.8		8.0	V
Q2 Drain-to-Source On Resistance	R _{DS(on)}	V _{ON/OFF} = 1.5 V V _{IN} = 4.5 V I _L = 1.2 A			130	175	mΩ
			V _{IN} = 2.5 V I _L = 1.0 A		170	220	
			V _{IN} = 1.8 V I _L = 0.7 A		260	320	
Load Current	lμ	$V_{DROP} \le 0.2 \text{ V}, V_{IN} = 5.0 \text{ V},$ $V_{ON/OFF} = 1.5 \text{ V}$ $V_{DROP} \le 0.3 \text{ V}, V_{IN} = 2.5 \text{ V},$ $V_{ON/OFF} = 1.5 \text{ V}$		1.0			Α
				1.0			

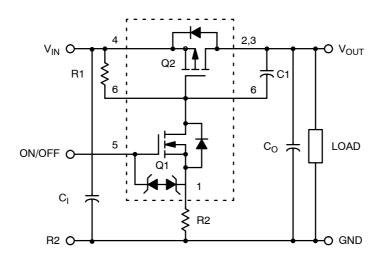
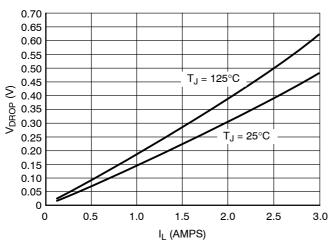


Figure 1. Load Switch Application

Components	Description	Values	
R1	Pullup Resistor	Typical 10 k Ω to 1.0 M Ω^*	
R2	Optional Slew-Rate Control	Typical 0 to 100 k Ω^*	
C _O , C _I	Output Capacitance	Usually < 1.0 μF	
C1	Optional In-Rush Current Control	Typical ≤ 1000 pF	

^{*}Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.

TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)



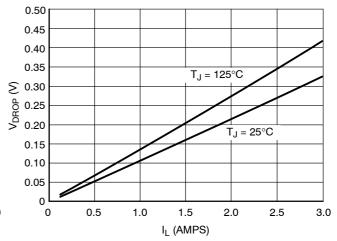
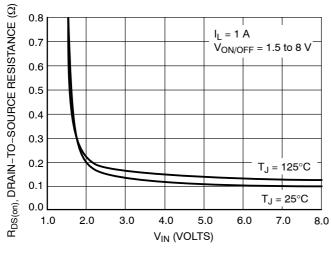


Figure 2. V_{drop} vs. $I_L @ V_{in} = 2.5 \text{ V}$

Figure 3. V_{drop} vs. $I_L @ V_{in} = 4.5 \text{ V}$



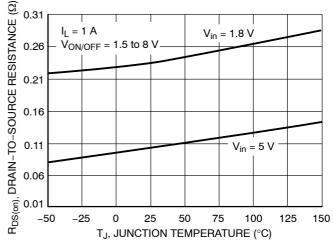
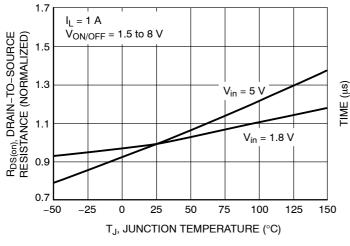


Figure 4. On-Resistance vs. Input Voltage

Figure 5. On-Resistance Variation with Temperature



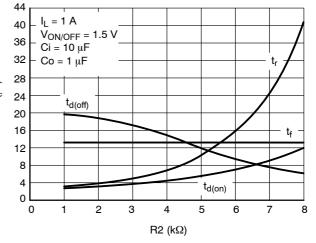


Figure 6. Normalized On-Resistance Variation with Temperature

Figure 7. Switching Variation R2 @ V_{in} = 4.5 V, R1 = 20 $k\Omega$

TYPICAL PERFORMANCE CURVES ($T_J = 25^{\circ}$ C unless otherwise noted)

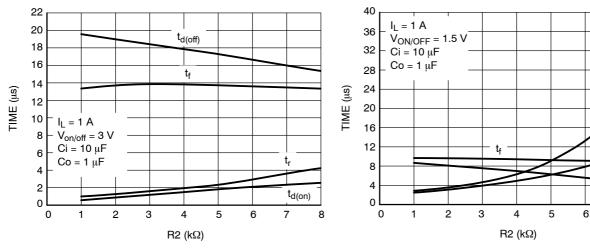


Figure 8. Switching Variation R2 @ V_{in} = 4.5 V, R1 = 20 k Ω

Figure 9. Switching Variation R2 @ V_{in} = 2.5 V, R1 = 20 k Ω

t_{d(on)}

t_{d(off)}

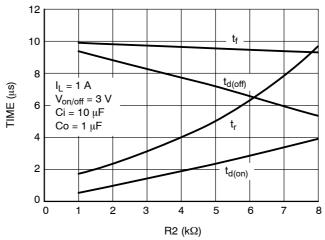


Figure 10. Switching Variation R2 @ V_{in} = 2.5 V, R1 = 20 $k\Omega$

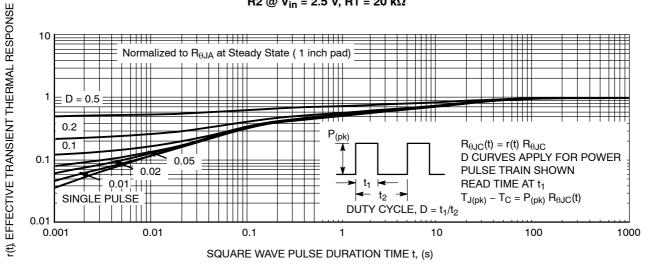
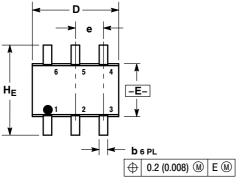


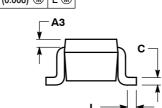
Figure 11. FET Thermal Response

NTJD1155L

PACKAGE DIMENSIONS

SC-88 (SOT-363) CASE 419B-02 **ISSUE W**





NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 419B-01 OBSOLETE, NEW STANDARD 419B-02.

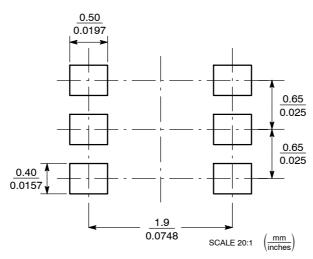
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.95	1.10	0.031	0.037	0.043	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
А3	0.20 REF			0.008 REF			
b	0.10	0.21	0.30	0.004	0.008	0.012	
С	0.10	0.14	0.25	0.004	0.005	0.010	
D	1.80	2.00	2.20	0.070	0.078	0.086	
Е	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65 BSC			0.026 BSC			
L	0.10	0.20	0.30	0.004	0.008	0.012	
He	2.00	2.10	2.20	0.078	0.082	0.086	

STYLE 30:

PIN 1. SOURCE 1

- 2. DRAIN 2
- 3. DRAIN 2
- 4 SOURCE 2 GATE 1
- 6 DRAIN 1

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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